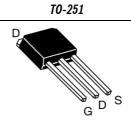
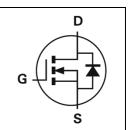




 $V_{DSS}$ , 30V

 $R_{DS(ON)}$  , 11.5m $\Omega$  (max.) @  $V_{GS}$ =10V  $R_{DS(ON)}$  , 17m $\Omega$  (max.) @  $V_{GS}$ =4.5V  $I_D$  , 40A





Description	Features
The SG30N051 uses advanced Trench technology and designs to provide excellent $R_{\text{DS(ON)}}$ with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.	<ul> <li>Low On-Resistance</li> <li>Low Input Capacitance</li> <li>Low Miller Charge</li> <li>Low Input/Output Leakage</li> </ul>
	Applications
	<ul> <li>Motor / Body Load Control</li> <li>Automotive Systems</li> <li>Load Switch</li> <li>DC-DC converters and Off-line UPS</li> </ul>

# **Ordering Information**

Ordering Code	RoHS Status	Package	Package Code	Packing	Quantity
SG30N05I	Halogen-Free	T0-251	I	Box (Tube)	6,750 (75)

# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise noted)

Parame	eter	Symbol	Value	Unit
Drain-Source Voltage		V <sub>DS</sub>	30	V
Gate-Source Voltage		V <sub>GS</sub>	±20	V
Drain Current-Continuous	T <sub>C</sub> =25°C		40	А
Diani Current-Continuous	$T_{\rm C} = 70^{\circ}{\rm C}$	I <sub>D</sub>	33.6	А
Drain Current-Pulsed Note 1	·	I <sub>DM</sub>	120	А
Drain Current-Continuous	T <sub>A</sub> =25°C	1	10.7	A
Diani Current-Continuous	$T_A = 70^{\circ}C$	I <sub>D</sub>	8.6	А
Avalanche Current, L=0.1mH		I <sub>AS</sub>	15	А
Avalanche Energy, L=0.1mH		E <sub>AS</sub>	11.25	mJ
	$T_{\rm C}{=}25^{\circ}{\rm C}$		30.4	W
Mayimum Dawar Dissination	T <sub>C</sub> =70°C	D	19.5	W
Maximum Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2	W
	T <sub>A</sub> =70°C		1.3	W
Storage Temperature Range		T <sub>STG</sub>	-55 to +150	°C
Operating Junction Temperature Range		T <sub>J</sub>	-55 to +150	°C

## Thermal Resistance Ratings

Parameter	Symbol	Conditions	Min.	Тур.	Мах.	Unit
Maximum Junction-to-Ambient Note 2	$R_{\theta_{JA}}$	Steady State	-	-	62	°C/W
Maximum Junction-to-Case	$R_{\theta_{JC}}$	Steady State	-	-	4.1	°C/W

1





# Electrical Characteristics (T<sub>j</sub>=25°C unless otherwise noted)

OFF CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Тур.	Мах.	Unit
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS} = 0V, I_{DS} = 250 \mu A$	30	-	-	٧
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}=24V, V_{GS}=0V$	=	-	1	μA
Gate-Body Leakage	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA

ON CHARACTERISTICS					ON CHARACTERISTICS							
Parameter	Symbol	Conditions	Min.	Тур.	Мах.	Unit						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$	1.2	-	2.5	V						
Drain-Source On-State Resistance	D	$V_{GS}=10V$ , $I_{DS}=10A$	-	9	11.5	mΩ						
Diain-Source on-State Resistance	N <sub>DS(ON)</sub>	$V_{GS}$ =4.5V, $I_{DS}$ =8A	-	13	17	mΩ						

DYNAMIC CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Тур.	Мах.	Unit
Input Capacitance	C <sub>iss</sub>		-	580	-	
Output Capacitance	C <sub>oss</sub>	$V_{DS}=15V$ , $V_{GS}=0V$ , $f=1MHz$	-	95	=	pF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	60	-	

SWITCHING CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Тур.	Мах.	Unit
Turn-On Delay Time	T <sub>d(on)</sub>		-	15	-	
Rise Time	t <sub>r</sub>	$V_{DD} = 15V$ , $I_{D} = 10A$ , $V_{GEN} = 4.5V$ ,	-	12	-	
Turn-Off Delay Time	$T_{d(off)}$	$Rg=3\Omega$	-	14	-	ns
Fall Time	t <sub>f</sub>		-	10	-	
Total Gate Charge at 10V	$Q_{\rm g}$		-	8	-	
Gate to Source Gate Charge	$Q_{\mathrm{gs}}$	$V_{DS} = 15V$ , $I_{DS} = 10A$ , $V_{GS} = 4.5V$	-	3	-	nC
Gate to Drain "Miller" Charge	$Q_{\mathrm{gd}}$		-	4.5	-	

DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS							
Parameter Symbol Conditions Min. Typ. Max. Unit							
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS} = 0V$ , $I_S = 10A$	-	-	1.3	V	
Body Diode Reverse Recovery Time	t <sub>rr</sub>	L _ 10A dl/dt_ 100A/ug	-	14	-	ns	
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> =10A, dl/dt=100A/µs	-	11	-	nC	

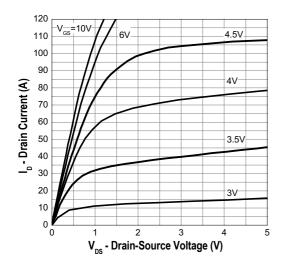
## Notes:

- 1. Pulse Test: Pulse Width  $\leq 300 \mu s$ , Duty Cycle  $\leq 2\%$ .
- 2.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.  $R_{\theta JA}$  shown below for single device operation on FR-4 in still air.

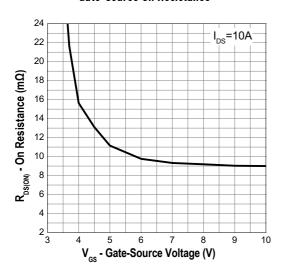


## **Typical Operating Characteristics**

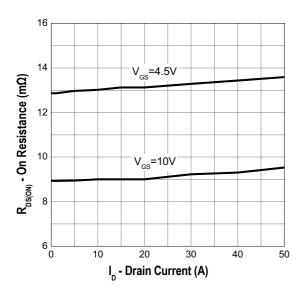
## **Output Characteristics**



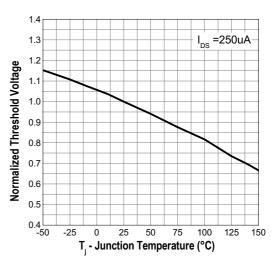
#### Gate-Source On Resistance



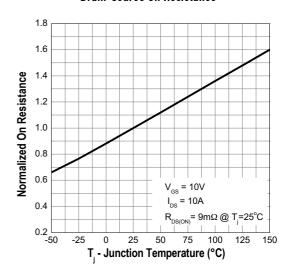
**Drain-Source On Resistance** 



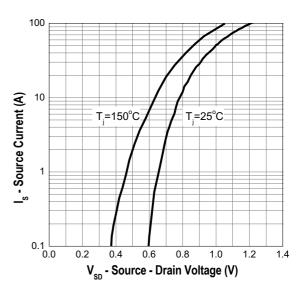
## Gate Threshold Voltage



Drain-Source On Resistance

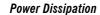


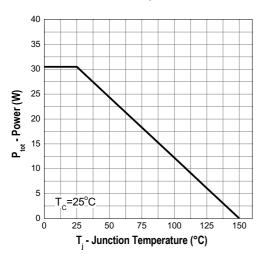
Source-Drain Diode Forward



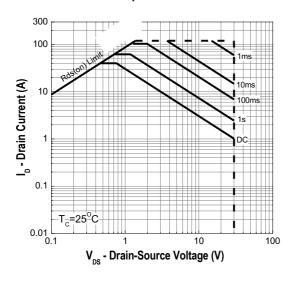


## Typical Operating Characteristics (Cont.)

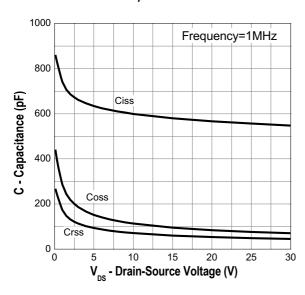




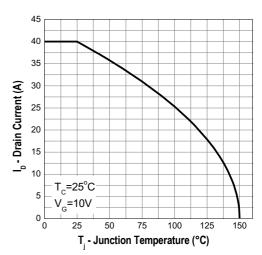
## Safe Operation Area



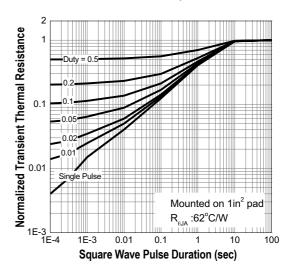
#### Capacitance



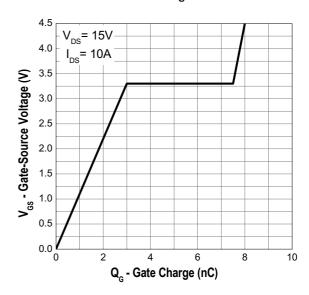
### Drain Current



#### Transient Thermal Impedance

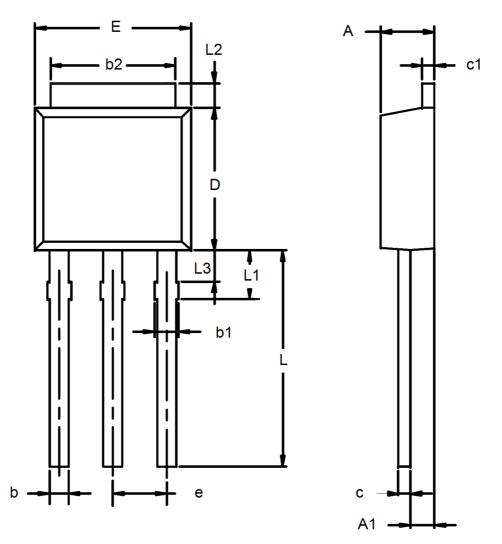


## Gate Charge





# Package Dimension



	Dimensions									
0		Millimeters			Inches					
Symbols	Min.	Тур.	Max.	Min.	Тур.	Max.				
Α	2.21	-	2.38	0.087	-	0.094				
A1	0.89	-	1.14	0.035	-	0.045				
b	0.71	-	0.89	0.028	-	0.035				
b1	0.76	-	1.14	0.030	-	0.045				
b2	5.23	-	5.43	0.206	-	0.214				
С	0.46	-	0.58	0.018	-	0.023				
c1	0.46	-	0.58	0.018	-	0.023				
D	5.97	-	6.22	0.235	-	0.245				
E	6.48	-	6.73	0.255	-	0.265				
е		2.28 BSC			0.090 BSC					
L	8.89	-	9.53	0.350	-	0.375				
L1	1.91	-	2.28	0.075	-	0.090				
L2	0.89	-	1.27	0.035	-	0.050				
L3	1.15	-	1.52	0.045	-	0.060				



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